

Data sheet acquired from Harris Semiconductor SCHS199C

February 1998 - Revised August 2004

High-Speed CMOS Logic Quad Bilateral Switch

Features

•	Wide Analog-	nput-Voltage	Range	0V to	10V
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• Low "ON" Resistance

-	45 Ω (Typ)	\dots $V_{CC} = 4.5V$
-	35 Ω (Typ)	V _{CC} = 6V
-	30 Ω (Typ)	1fcV _{CC} = 9V

- Fast Switching and Propagation Delay Times
- Low "OFF" Leakage Current
- · Built-In "Break-Before-Make" Switching
- Suitable for Sample and Hold Applications
- Wide Operating Temperature Range . . . -55°C to 125°C
- HC Types
 - 2V to 10V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V

Description

The CD74HC4016 contains four independent digitally controlled analog switches that use silicon-gate CMOS technology to achieve operating speeds similar to LSTTL with the low power consumption of standard CMOS integrated circuits.

Each switch has two input/output terminals (nY, nZ) and an active high enable input (nE). Current through the switch will not cause additional V_{CC} current provided the analog voltage is maintained between V_{CC} and GND.

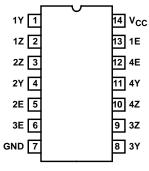
Ordering Information

PART NUMBER	TEMP. RANGE (^O C)	PACKAGE
CD74HC4016E	-55 to 125	14 Ld PDIP
CD74HC4016M	-55 to 125	14 Ld SOIC
CD74HC4016MT	-55 to 125	14 Ld SOIC
CD74HC4016M96	-55 to 125	14 Ld SOIC
CD74HC4016PW	-55 to 125	14 Ld TSSOP
CD74HC4016PWR	-55 to 125	14 Ld TSSOP

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250

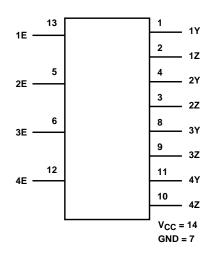
Pinout

CD74HC4016 (PDIP, SOIC, TSSOP) TOP VIEW



CD74HC4016

Functional Diagram

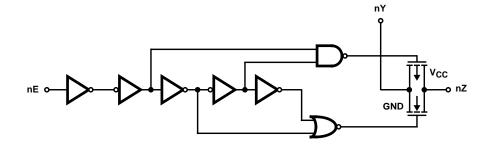


TRUTH TABLE

INPUT nE	SWITCH
L	OFF
Н	ON

H = High Level Voltage L = Low Level Voltage

Logic Diagram



CD74HC4016

Absolute Maximum Ratings

DC Supply Voltage, V $_{CC}$... -0.5V to 7V DC Input Diode Current, I $_{IK}$ For V $_{I}$ <-0.5V or V $_{I}$ > V $_{CC}$ + 0.5V ± 20 mA DC Drain Current, per Output, I $_{O}$ For -0.5V < V $_{O}$ < V $_{CC}$ + 0.5V ± 25 mA DC Output Diode Current, I $_{OK}$ For V $_{O}$ <-0.5V or V $_{O}$ > V $_{CC}$ + 0.5V ± 20 mA DC Output Source or Sink Current per Output Pin, I $_{O}$ For V $_{O}$ >-0.5V or V $_{O}$ < V $_{CC}$ + 0.5V ± 25 mA DC V $_{CC}$ or Ground Current, I $_{CC}$... ± 25 mA

Thermal Information

Thermal Resistance (Typical, Note 1)	θ _{JA} (°C/W)
E (PDIP) Package	80
M (SOIC) Package	86
PW (TSSOP) Package	96
Maximum Junction Temperature (Plastic Package)	150 ^o C
Maximum Storage Temperature Range65	5°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C

Operating Conditions

Temperature Range, T _A 55	^o C to 125 ^o C
Supply Voltage Range, V _{CC}	
HC Types	2V to 10V
DC Input or Output Voltage, V _I , V _O	. 0V to V_{CC}
Input Rise and Fall Time	
2V	000ns (Max)
4.5V	500ns (Max)
6V	400ns (Max)
9V	250ns (Max)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implie

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TES	CONDIT	IONS	S 25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	V _{IS} (V)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	٧
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	i	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
"ON" Resistance	R _{ON}	V _{IH} or	V _{CC} or GND	4.5	ı	45	180	i	225	-	270	Ω
I _O = 1mA		V _{IL}		6	ı	35	160	ı	200	-	240	Ω
				9	-	30	135	-	170	-	205	Ω
				4.5	-	85	320	-	400	-	480	Ω
				6	-	55	240	i	300	-	360	Ω
				9	-	35	170	-	215	-	255	Ω
Maximum "ON" Resistance Between	ΔR _{ON}	V _{IL} or	V _{CC} or GND	4.5	-	10	-	-	-	-	-	Ω
Any Two Switches		V _{IH}	GND	6	-	8.5	-	-	-	-	-	Ω
Switch Off Leakage	I _{IZ}	En =	V _{CC} or	6	-	-	±0.1	-	±1	-	±1	μА
Current		GND	GND	10	-	-	±0.1	-	±1	-	±1	μА
Logic Input Leakage Current	II	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μА

CD74HC4016

DC Electrical Specifications (Continued)

		TEST	CONDIT	25°C			-40°C TO 85°C		-55°C TO 125°C			
PARAMETER	SYMBOL	V _I (V)	V _{IS} (V)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Quiescent Device	Icc	V _{CC} or	V _{CC} or	6	-	-	2	-	20	-	40	μА
Current I _O = 0mA		GND	GND	10	-	-	16	-	160	-	320	μА

Switching Specifications Input t_r , $t_f = 6ns$

		TEST	Vaa	25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	МАХ	MIN	MAX	MIN	MAX	UNITS
HC TYPES											
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	60	-	75	-	90	ns
Switch In to Switch Out			4.5	-	-	12	-	15	-	18	ns
		C _L = 15pF	5	-	4	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	10	-	13	-	15	ns
			9	-	-	8	-	10	-	12	ns
Propagation Delay,	t _{PZH} , t _{PZL}	C _L = 50pF	2	-	-	190	-	240	-	285	ns
Switch Turn-On En to Out			4.5	-	-	38	-	48	-	57	ns
		C _L = 15pF	5	-	16	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	32	-	41	-	48	ns
			9	-	-	28	-	35	-	42	ns
Propagation Delay,	t _{PHZ} , t _{PLZ}	C _L = 50pF	2	-	-	145	-	180	-	220	ns
Switch Turn-Off En to Out			4.5	-	-	29	-	36	-	44	ns
		C _L = 15pF	5	-	12	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	25	-	31	-	38	ns
			9	-	-	22	-	28	-	33	ns
Input Capacitance	C _I	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 2, 3)	C _{PD}	-	5	-	12	-	-	-	-	-	pF

NOTES:

- 2. $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per package.
- P_D = C_{PD} V_{CC}² f_i + Σ (C_L + C_S) V_{CC}² f_o where f_i = input frequency, f_o = output frequency, C_L = output load capacitance, C_S = switch capacitance, V_{CC} = supply voltage.

Analog Channel Specifications $T_A = 25^{\circ}C$

PARAMETER	TEST CONDITIONS	V _{CC} (V)	CD74HC4016	UNITS
Switch Frequency Response Bandwidth at -3dB Figure 3	Figure 6, Notes 4, 5	4.5	>200	MHz
Crosstalk Between Any Two Switches, Figure 4	Figure 5, Notes 5, 6	4.5	TBE	dB
Total Harmonic Distortion	1kHz, V _{IS} = 4V _{P-P} Figure 7	4, 5	0.078	%
	1kHz, V _{IS} = 8V _{P-P} Figure 7	9	0.018	%

Analog Channel Specifications $T_A = 25^{\circ}C$ (Continued)

PARAMETER	TEST CONDITIONS	V _{CC} (V)	CD74HC4016	UNITS
Control to Switch Feedthrough Noise	Figure 8	4.5	TBE	mV
		9	TBE	mV
Switch "OFF" Signal Feedthrough, Figure 4	Figure 9, Notes 5, 6	4.5	-62	dB
Switch Input Capacitance, C _S		-	5	pF

NOTES:

- 4. Adjust input level for 0dBm at output, f = 1MHz.
- 5. $V_{\mbox{\scriptsize IS}}$ is centered at $V_{\mbox{\scriptsize CC}}/2$.
- 6. Adjust input for 0dBm at $V_{\mbox{\scriptsize IS}}.$

Typical Performance Curves

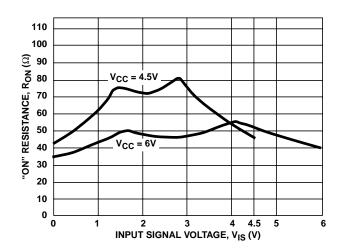


FIGURE 1. TYPICAL "ON" RESISTANCE vs INPUT SIGNAL VOLTAGE

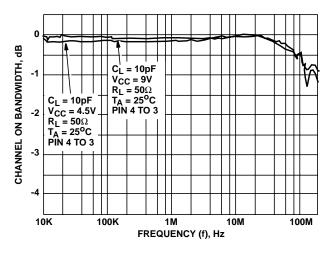


FIGURE 3. SWITCH FREQUENCY RESPONSE

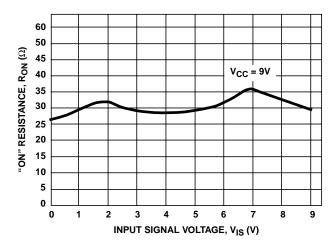


FIGURE 2. TYPICAL "ON" RESISTANCE vs INPUT SIGNAL VOLTAGE

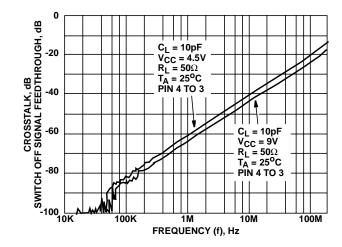
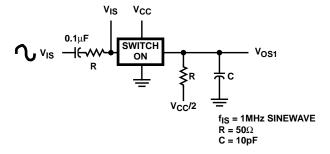


FIGURE 4. SWITCH-OFF SIGNAL FEEDTHROUGH AND CROSSTALK vs FREQUENCY

Analog Test Circuits



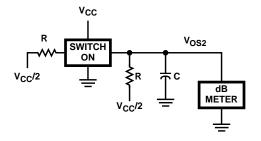
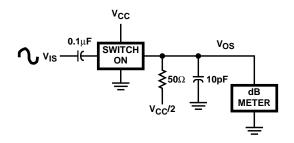


FIGURE 5. CROSSTALK BETWEEN TWO SWITCHES TEST CIRCUIT



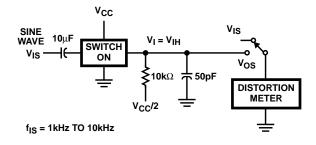
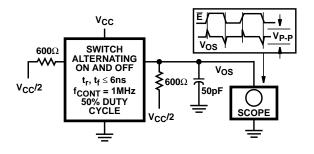


FIGURE 6. FREQUENCY RESPONSE TEST CIRCUIT

FIGURE 7. TOTAL HARMONIC DISTORTION TEST CIRCUIT



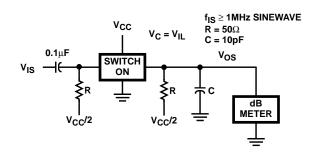
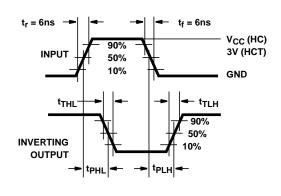


FIGURE 8. CONTROL-TO-SWITCH FEEDTHROUGH NOISE TEST CIRCUIT

FIGURE 9. SWITCH OFF SIGNAL FEEDTHROUGH

Test Circuits and Waveforms



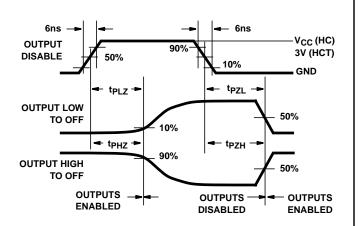


FIGURE 10. HC/HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

FIGURE 11. SWITCH TURN-ON AND TURN-OFF PROPAGATION DELAY TIMES

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HC4016E	NRND	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4016E	
CD74HC4016E	INKIND	PUIF	IN	14	25	KUNS & GIEEH	NIPDAU	N/A lot Fkg Type	-55 10 125	CD74HC4016E	
CD74HC4016M96	NRND	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4016M	
CD74HC4016MT	NRND	SOIC	D	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4016M	
CD74HC4016PW	NRND	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HP14	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC4016M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HC4016MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC4016M96	SOIC	D	14	2500	356.0	356.0	35.0
CD74HC4016MT	SOIC	D	14	250	210.0	185.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74HC4016E	N	PDIP	14	25	506	13.97	11230	4.32
CD74HC4016E	N	PDIP	14	25	506	13.97	11230	4.32
CD74HC4016PW	PW	TSSOP	14	90	530	10.2	3600	3.5

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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